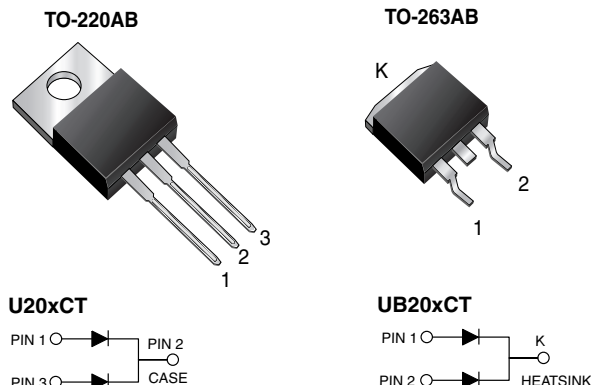


## Dual Common Cathode Ultrafast Plastic Rectifier



### FEATURES

- Power pack
- Oxide planar chip junction
- Ultrafast recovery time
- Soft recovery characteristics
- Low switching losses, high efficiency
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s per JESD 22-B106 (for TO-220AB package)
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, DC/DC converters or polarity protection specifically for DCM application.

### MECHANICAL DATA

**Case:** TO-220AB, TO-263AB

Molding compound meets UL 94V-0 flammability rating  
Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs max.

| PRIMARY CHARACTERISTICS |                     |
|-------------------------|---------------------|
| $I_{F(AV)}$             | 2 x 10 A            |
| $V_{RRM}$               | 100 V to 200 V      |
| $I_{FSM}$               | 100 A               |
| $t_{rr}$                | 26 ns               |
| $V_F$ at $I_F = 10$ A   | 0.834 V             |
| $T_J$ max.              | 150 °C              |
| Package                 | TO-220AB, TO-263AB  |
| Diode variation         | Dual Common Cathode |

| MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)                                    |                                   |             |           |           |      |
|----------------------------------------------------------------------------------------------------|-----------------------------------|-------------|-----------|-----------|------|
| PARAMETER                                                                                          | SYMBOL                            | U(B)20BCT   | U(B)20CCT | U(B)20DCT | UNIT |
| Max. repetitive peak reverse voltage                                                               | V <sub>RRM</sub>                  | 100         | 150       | 200       | V    |
| Max. average forward rectified current (fig. 1) <div>total device</div> <div>per diode</div>       | I <sub>F(AV)</sub>                | 20          |           |           | A    |
|                                                                                                    |                                   | 10          |           |           |      |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode        | I <sub>FSM</sub>                  | 100         |           |           | A    |
| Electrostatic discharge capacitor voltage, human body model: C = 150 pF, R = 1.5 kΩ (contact mode) | V <sub>C</sub>                    | 8           |           |           | kV   |
| Operating junction and storage temperature range                                                   | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 |           |           | °C   |

| ELECTRICAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted) |                                                                                                          |                         |                 |       |      |      |
|----------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------|-------------------------|-----------------|-------|------|------|
| PARAMETER                                                                  | TEST CONDITIONS                                                                                          |                         | SYMBOL          | TYP.  | MAX. | UNIT |
| Instantaneous forward voltage per diode <sup>(1)</sup>                     | I <sub>F</sub> = 5.0 A                                                                                   | T <sub>J</sub> = 25 °C  | V <sub>F</sub>  | 0.854 | -    | V    |
|                                                                            | I <sub>F</sub> = 10 A                                                                                    |                         |                 | 0.931 | 1.00 |      |
|                                                                            | I <sub>F</sub> = 5.0 A                                                                                   | T <sub>J</sub> = 100 °C |                 | 0.760 | -    |      |
|                                                                            | I <sub>F</sub> = 10 A                                                                                    |                         |                 | 0.834 | 0.91 |      |
| Reverse current per diode <sup>(2)</sup>                                   | rated V <sub>R</sub>                                                                                     | T <sub>J</sub> = 25 °C  | I <sub>R</sub>  | 1.2   | 15   | μA   |
|                                                                            |                                                                                                          | T <sub>J</sub> = 100 °C |                 | 120   | 500  |      |
| Reverse recovery time per diode                                            | I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A                                 |                         | t <sub>rr</sub> | 26    | 35   | ns   |
| Reverse recovery time per diode                                            | I <sub>F</sub> = 10 A, dI/dt = 20 A/μs,<br>V <sub>R</sub> = 200 V, I <sub>rr</sub> = 0.1 I <sub>RM</sub> |                         | t <sub>rr</sub> | 73    | 80   | ns   |
| Stored charge per diode                                                    |                                                                                                          |                         | Q <sub>rr</sub> | 30    | -    | nC   |
| Forward recovery time per diode                                            | I <sub>F</sub> = 10 A, dI/dt = 80 A/μs,<br>V <sub>F</sub> = 1.1 x V <sub>F</sub> max.                    |                         | t <sub>fr</sub> | 160   | -    | ns   |
| Peak forward voltage per diode                                             |                                                                                                          |                         | V <sub>FP</sub> | 2.6   | -    | V    |

**Notes**
<sup>(1)</sup> Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq 40\text{ ms}$ 

| <b>THERMAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |                 |        |         |                             |
|---------------------------------------------------------------------------------------------|-----------------|--------|---------|-----------------------------|
| PARAMETER                                                                                   | SYMBOL          | U20xCT | UB20xCT | UNIT                        |
| Typical thermal resistance per diode                                                        | $R_{\theta JC}$ | 3.0    |         | $^{\circ}\text{C}/\text{W}$ |

| <b>ORDERING INFORMATION</b> (Example) |               |                 |              |               |               |
|---------------------------------------|---------------|-----------------|--------------|---------------|---------------|
| PACKAGE                               | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-220AB                              | U20DCT-E3/4W  | 1.87            | 4W           | 50/tube       | Tube          |
| TO-263AB                              | UB20DCT-E3/4W | 1.37            | 4W           | 50/tube       | Tube          |
| TO-263AB                              | UB20DCT-E3/8W | 1.37            | 8W           | 800/reel      | Tape and reel |

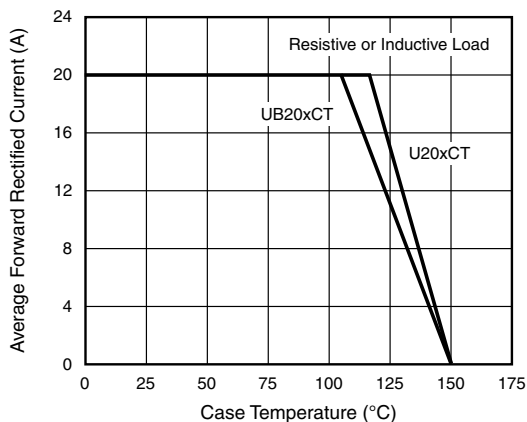
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)


Fig. 1 - Max. Forward Current Derating Curve

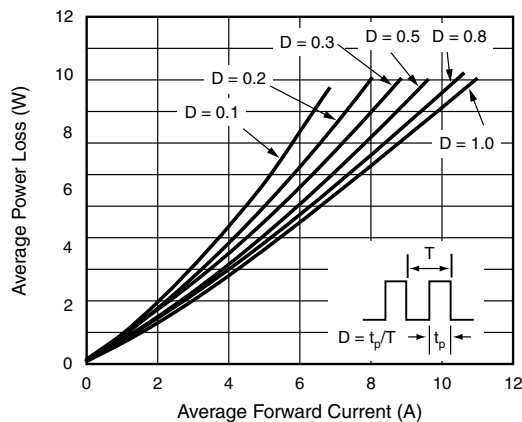


Fig. 2 - Forward Power Loss Characteristics Per Diode

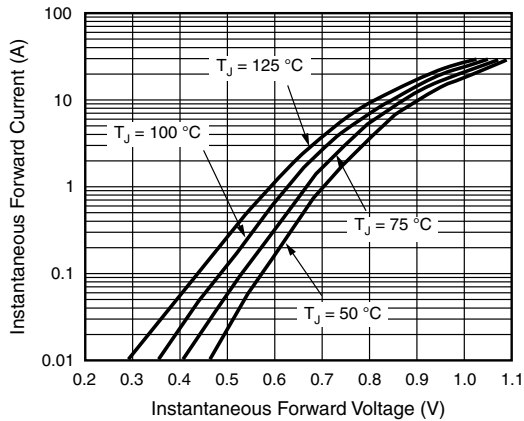


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

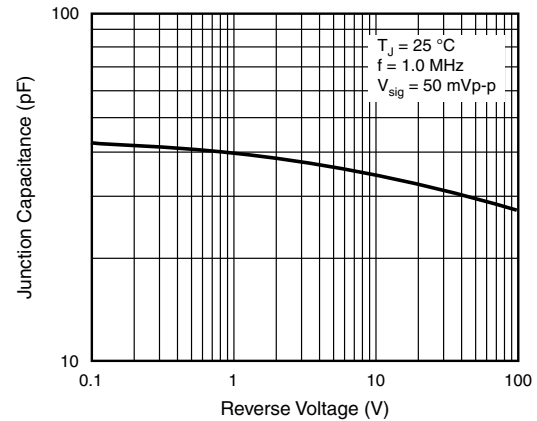


Fig. 5 - Typical Junction Capacitance Per Diode

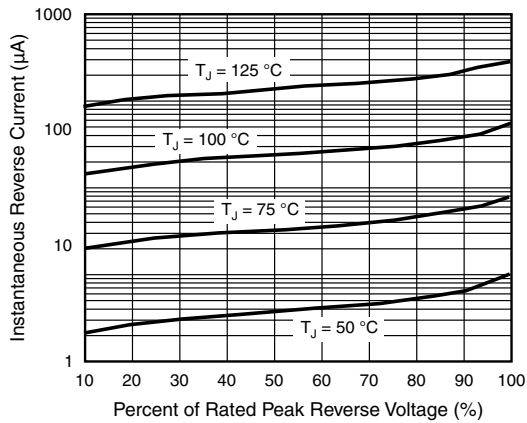


Fig. 4 - Typical Reverse Characteristics Per Diode

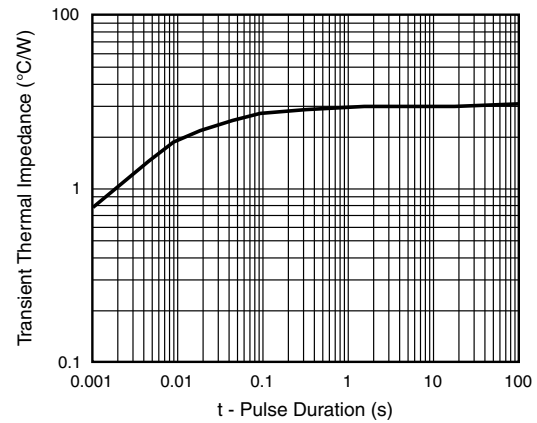
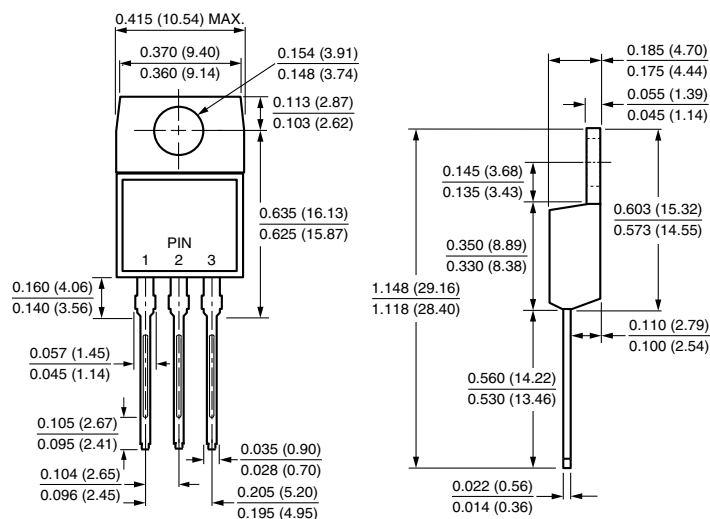


Fig. 6 - Typical Junction Capacitance Per Diode

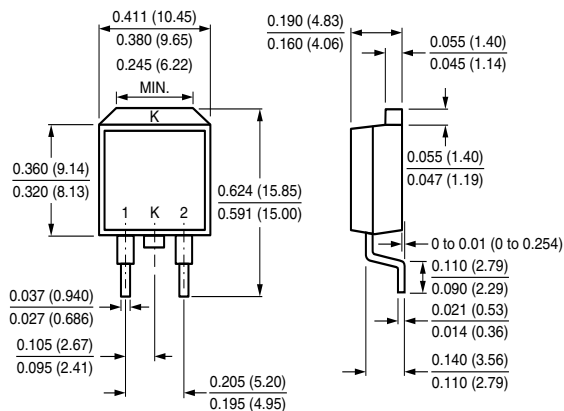


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

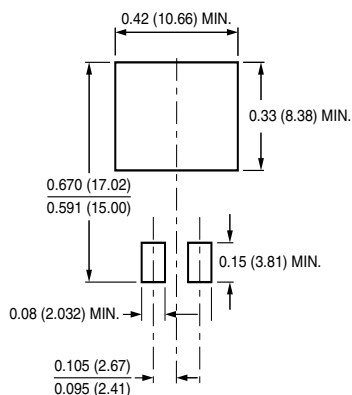
### TO-220AB



### TO-263AB



### Mounting Pad Layout





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